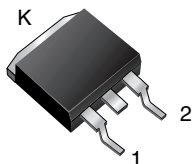
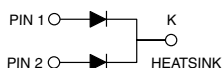


Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

D²PAK (TO-263AB)

MBRB30HxxCT


FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available
- Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified
("X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 15 A
V_{RRM}	45 V, 60 V
I_{FSM}	150 A
V_F	0.56 V, 0.59 V
I_R	80 μ A, 60 μ A
T_J max.	175 °C
Package	D ² PAK (TO-263AB)
Circuit configuration	Common cathode

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBRB30H45CT	MBRB30H60CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	60	V
Working peak reverse voltage	V_{RWM}	45	60	V
Maximum DC blocking voltage	V_{DC}	45	60	V
Maximum average forward rectified current (fig. 1) total device per diode	$I_{F(AV)}$	30 15		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150		A
Peak repetitive reverse surge current per diode at $t_p = 2$ μ s, 1 kHz	I_{RRM}	1.0	0.5	A
Peak non-repetitive reverse energy (8/20 μ s waveform)	E_{RSM}	25	20	mJ
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, $L = 10$ mH	E_{AS}	80		mJ
Electrostatic discharge capacitor voltage human body model: $C = 100$ pF, $R = 1.5$ k Ω	V_C	25		kV
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175		°C

**ELECTRICAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	MBRB30H45CT		MBRB30H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	$I_F = 15\text{ A}$	$T_C = 25\text{ }^{\circ}\text{C}$	$V_F^{(1)}$	-	0.62	-	0.68	V
	$I_F = 15\text{ A}$	$T_C = 125\text{ }^{\circ}\text{C}$		0.49	0.56	0.55	0.59	
	$I_F = 30\text{ A}$	$T_C = 25\text{ }^{\circ}\text{C}$		-	0.73	-	0.83	
	$I_F = 30\text{ A}$	$T_C = 125\text{ }^{\circ}\text{C}$		0.62	0.67	0.68	0.71	
Maximum reverse current per diode at working peak reverse voltage		$T_J = 25\text{ }^{\circ}\text{C}$	$I_R^{(2)}$	-	80	-	60	μA
		$T_J = 125\text{ }^{\circ}\text{C}$		5.0	15	4.0	15	mA

Notes(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: pulse width $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBRB	UNIT
Typical thermal resistance junction to case per diode	$R_{\theta JC}$	1.5	$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	MBRB30H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB30H45CT-E3/81	1.35	81	800/reel	Tape and reel
TO-263AB	MBRB30H45CTHE3_B/P ⁽¹⁾	1.35	P	50/tube	Tube
TO-263AB	MBRB30H45CTHE3_B/I ⁽¹⁾	1.35	I	800/reel	Tape and reel

Notes

(1) AEC-Q101 qualified

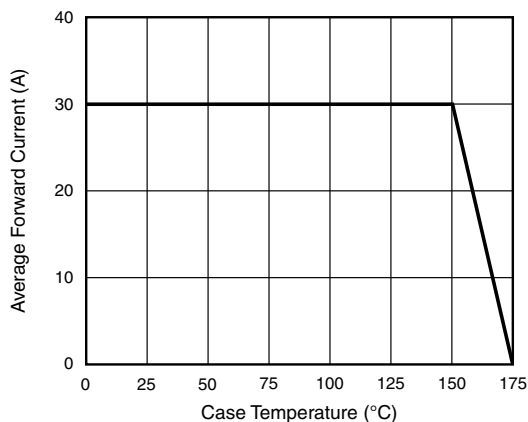
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Forward Derating Curve

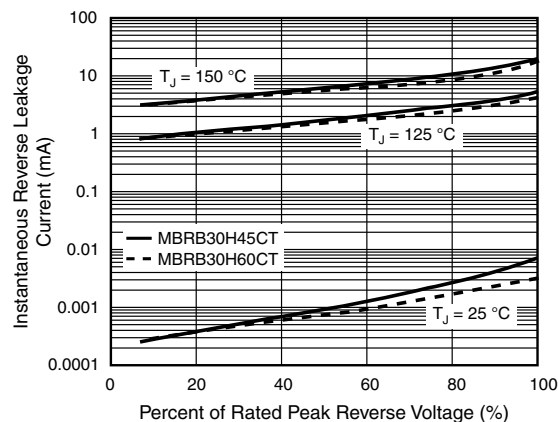


Fig. 4 - Typical Reverse Characteristics Per Diode

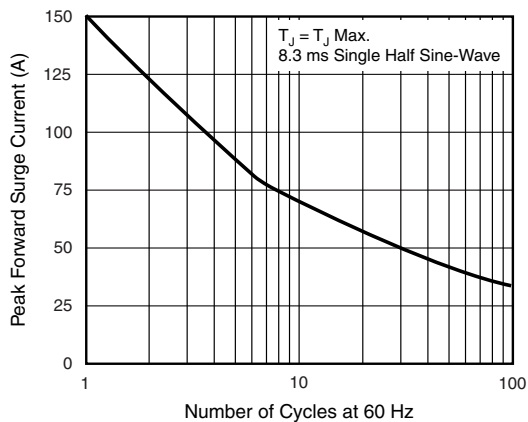


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

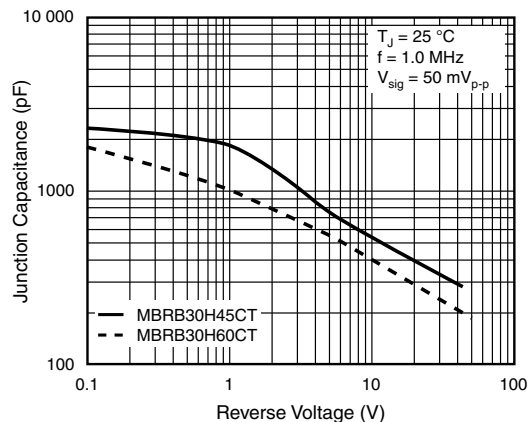


Fig. 5 - Typical Junction Capacitance Per Diode

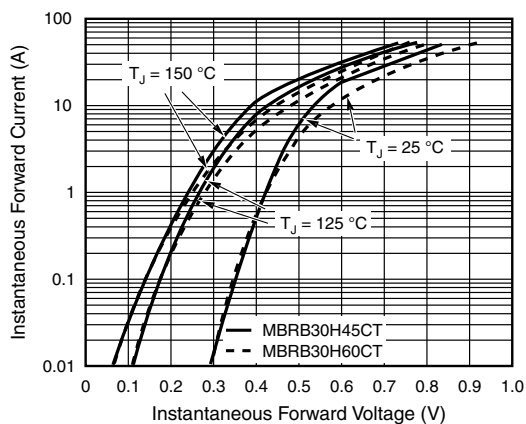


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

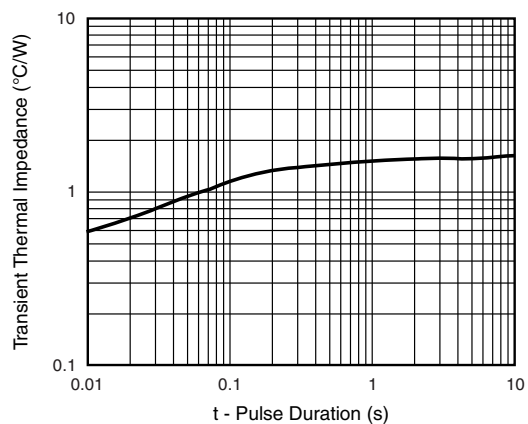
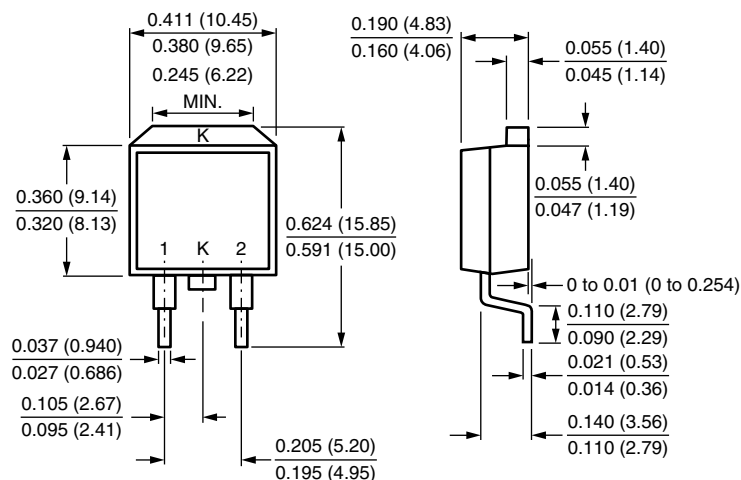


Fig. 6 - Typical Transient Thermal Impedance Per Diode

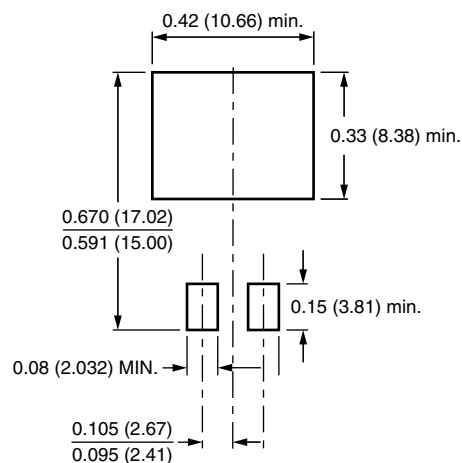


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)



Mounting Pad Layout





Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Vishay:](#)

[MBRB30H45CT-E3/81](#) [MBRB30H60CT-E3/81](#) [MBRF30H45CTHE3_A/P](#) [MBRB30H60CTHE3_B/P](#)
[MBRB30H45CTHE3_B/I](#) [MBRB30H60CTHE3_B/I](#) [MBRB30H45CTHE3_B/P](#) [MBRB30H60CT-E3/45](#)
[MBRB30H45CTHM3/I](#)